TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM6N15FE

High Speed Switching Applications Analog Switching Applications

- Small package
- Low ON resistance $: R_{on} = 4.0 \Omega \text{ (max)} (@V_{GS} = 4 \text{ V})$ $: R_{on} = 7.0 \Omega \text{ (max)} (@V_{GS} = 2.5 \text{ V})$

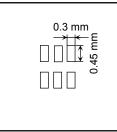
Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25° C)		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

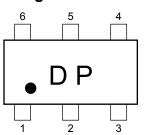
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

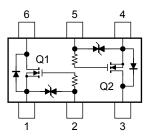
Note 1: Total rating, mounted on FR4 board (25.4 mm \times 25.4 mm \times 1.6 t, Cu Pad: 0.135 mm $^2 \times$ 6)



Marking

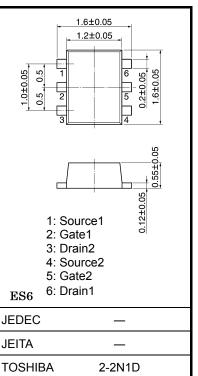


Equivalent Circuit (top view)



Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.



Weight: 3mg (typ.)

1

Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

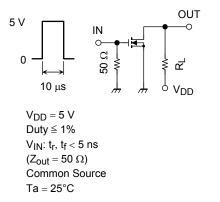
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$			±1	μA
Drain-Source breakdown voltage		V (BR) DSS	I _D = 0.1 mA, V _{GS} = 0	30			V
Drain cut-off current		IDSS	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0$			1	μA
Gate threshold voltage	e	V _{th}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.8		1.5	V
Forward transfer admi	ittance	Y _{fs}	V _{DS} = 3 V, I _D = 10 mA	25			mS
Drain-Source ON resistance		R _{DS (ON)}	I _D = 10 mA, V _{GS} = 4 V		2.2	4.0	Ω
			$I_{D} = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$		4.0	7.0	
Input capacitance		C _{iss}			7.8		pF
Reverse transfer capacitance		C _{rss}	V _{DS} = 3 V, V _{GS} = 0, f = 1 MHz		3.6		pF
Output capacitance		C _{oss}	1		8.8		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 5 \text{ V}, \text{ I}_{D} = 10 \text{ mA},$		50		ns
	Turn-off time	t _{off}	V _{GS} = 0~5 V		180		

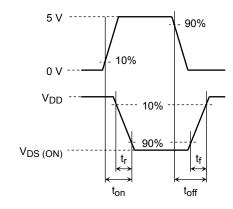
(b) V_{IN}

(c) VOUT

Switching Time Test Circuit

(a) Test circuit





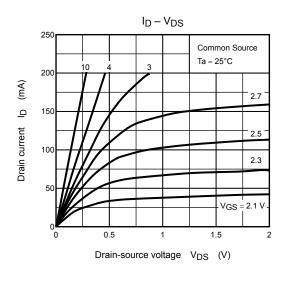
Precaution

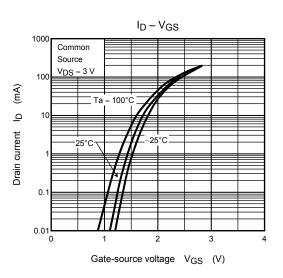
 $V_{th} \mbox{ can be expressed as voltage between gate and source when low operating current value is I_D = 100 \ \mu A \mbox{ for this product. For normal switching operation, V_{GS} (_{on}) requires higher voltage than V_{th} and V_{GS} (_{off}) requires lower voltage than V_{th}. (Relationship can be established as follows: V_{GS} (_{off}) < V_{th} < V_{GS} (_{on})$)

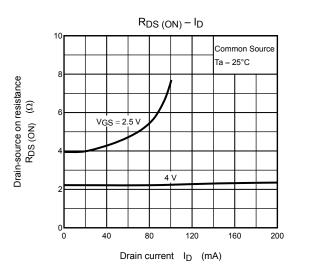
Please take this into consideration for using the device.

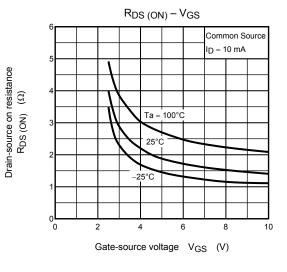
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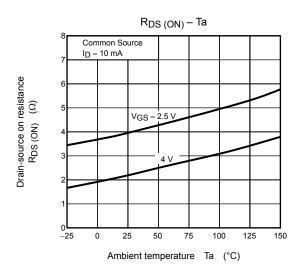
(Q1, Q2 Common)

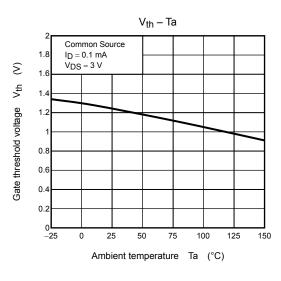






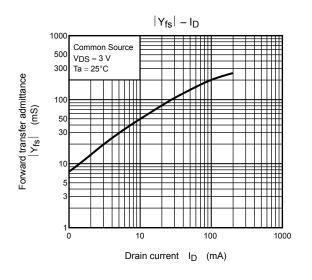


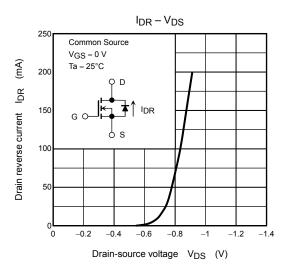


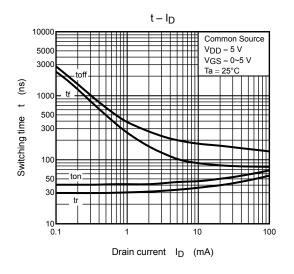


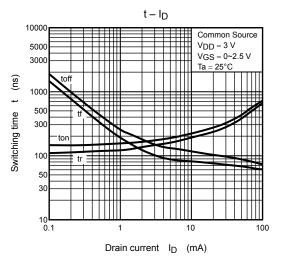
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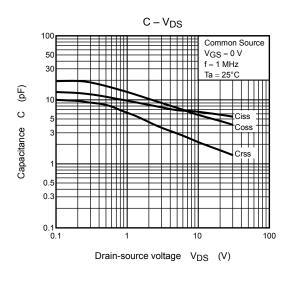
(Q1, Q2 Common)

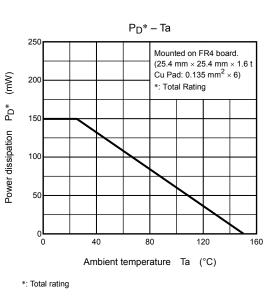












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